TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

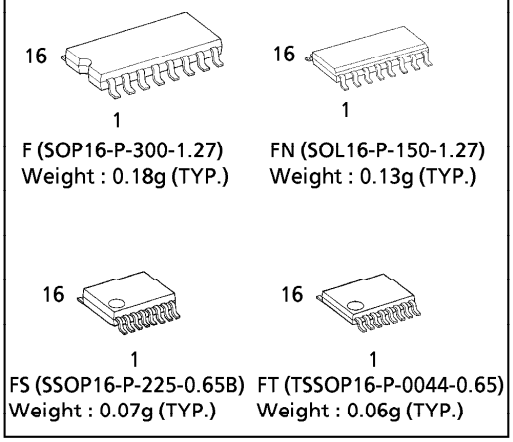
TC74VHC165F, TC74VHC165FN, TC74VHC165FS, TC74VHC165FT

8 - BIT SHIFT REGISTER (P - IN, S - OUT)

The TC74VHC165 is an advanced high speed CMOS 8-BIT PARALLEL/SERIAL-IN, SERIAL-OUT SHIFT REGISTER fabricated with silicon gate C2MOS technology.
It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.
It consists of parallel-in or serial-in, serial-out 8 - bit shift register with a gated clock input. When the SHIFT/$\overline{\text{LOAD}}$ input is held high, the serial data input is enabled and the eight frip-frops perform serial shifting with each clock pulse.
When the SHIFT/$\overline{\text{LOAD}}$ input is held low, the parallel data is loaded synchronously into the register at positive going transition of the clock pulse.
The CK-INH input should be shifted high only when the CK input is held high.
An Input protection circuit ensures that 0 to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and on two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

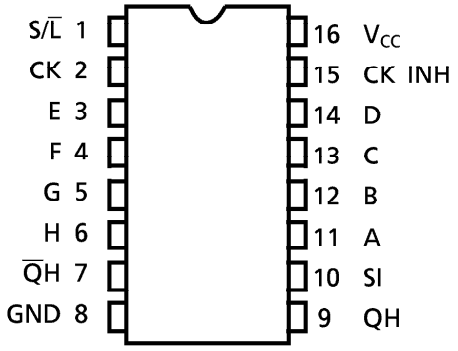
FEATURES :

- High Speed ..... f_{MAX} = 150MHz(typ.) at V_{CC} = 5V
- Low Power Dissipation ..... I_{CC} = 4μA(Max.) at Ta = 25°C
- High Noise Immunity..... $V_{NIH} = V_{NIL}$ = 28% V_{CC} (Min.)
- Power Down Protection is provided on all inputs.
- Balanced Propagation Delays.....$t_{pLH} \simeq t_{pHL}$
- Wide Operating Voltage Range....V_{CC} (opr) = 2V ~ 5.5V
- Pin and Function Compatible with 74ALS165



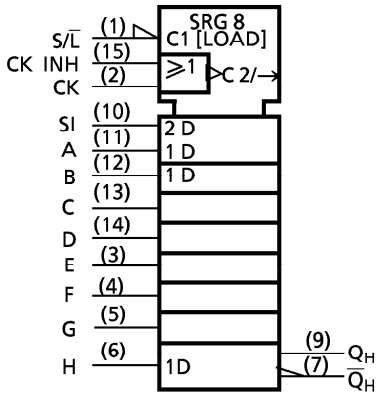
F (SOP16-P-300-1.27) Weight : 0.18g (TYP.)
FN (SOL16-P-150-1.27) Weight : 0.13g (TYP.)
FS (SSOP16-P-225-0.65B) Weight : 0.07g (TYP.)
FT (TSSOP16-P-0044-0.65) Weight : 0.06g (TYP.)

PIN ASSIGNMENT



(TOP VIEW)

IEC LOGIC SYMBOL



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TRUTH TABLE

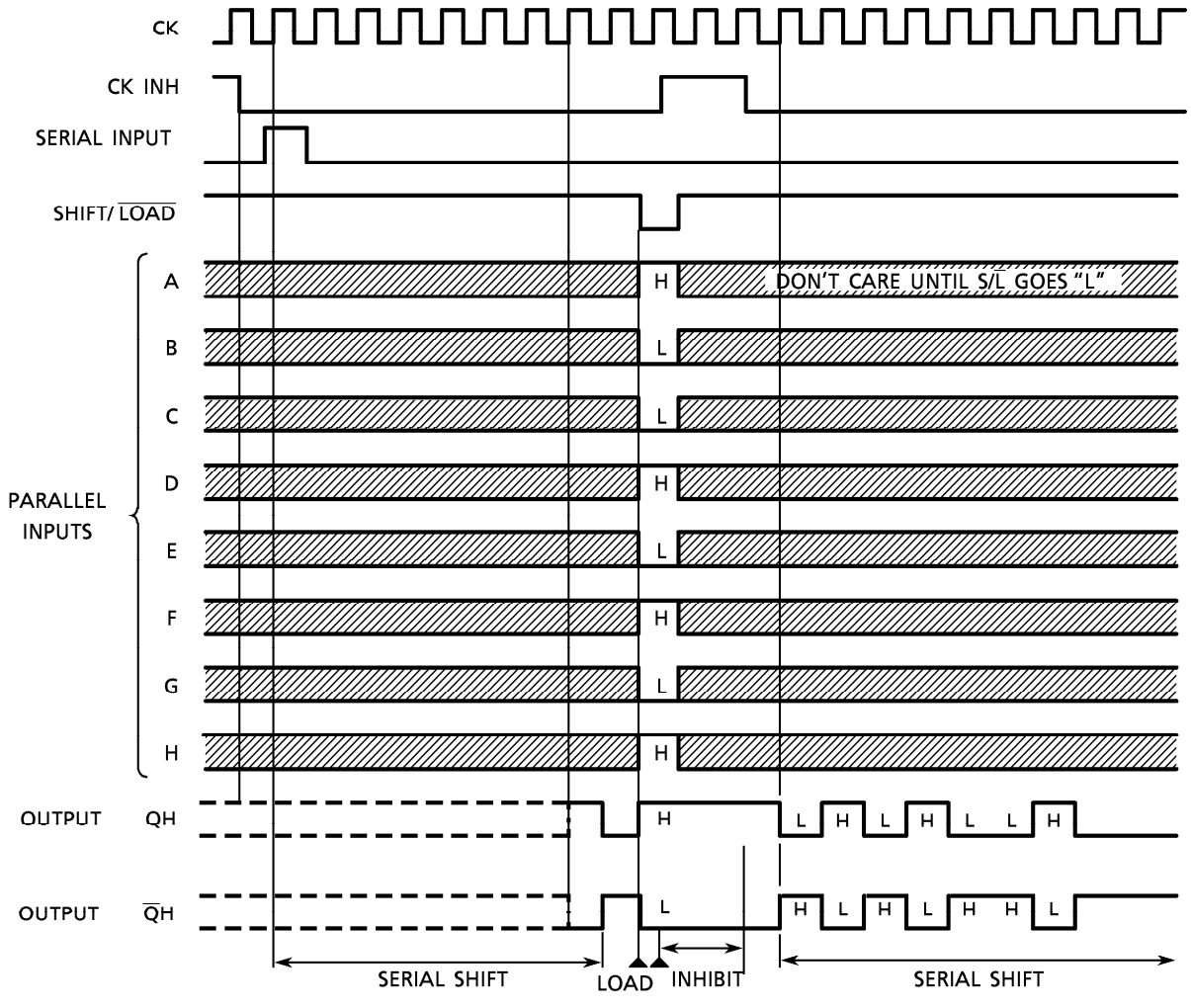
INPUTS					INTERNAL OUTPUTS		OUTPUT	
SHIFT/ LOAD	CLOCK INH	CLOCK	SERIAL IN	PARALLEL A …… H	QA	QB	QH	$\overline{Q}$H
L	X	X	X	a …… h	a	b	h	$\overline{h}$
H	L	↑	H	X	H	QAn	QGn	$\overline{Q}$Gn
H	L	↑	L	X	L	QAn	QGn	$\overline{Q}$Gn
H	↑	L	H	X	H	QAn	QGn	$\overline{Q}$Gn
H	↑	L	L	X	L	QAn	QGn	$\overline{Q}$Gn
H	X	H	X	X	NO CHANGE			
H	H	X	X	X	NO CHANGE			

X : Don't Care

a …… h : The level of steady state input voltage at inputs A through H respectively

QAn~QGn : The level of QA~QG, respectively, before the most recent positive transition of the CK.

TIMING CHART



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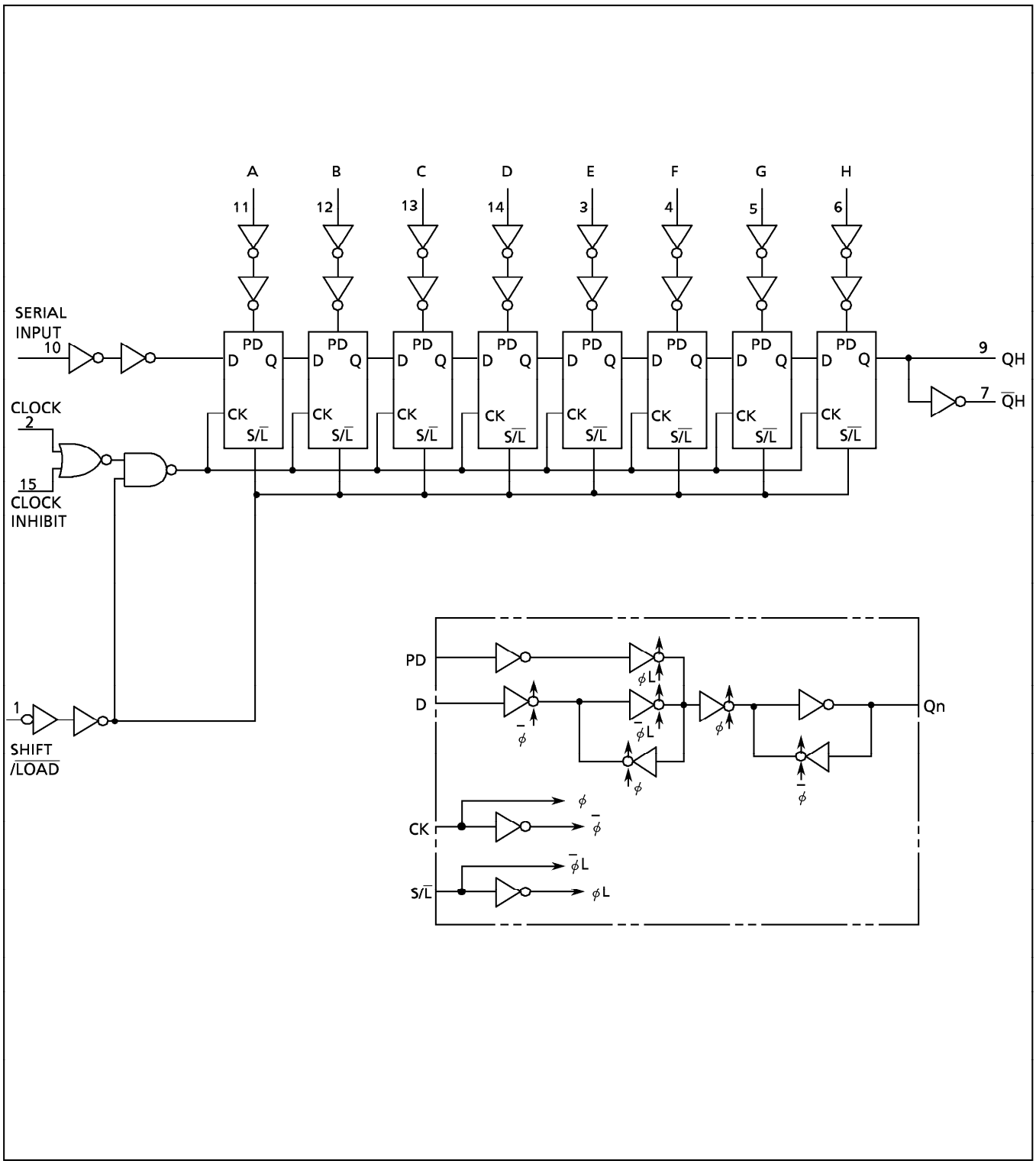
SYSTEM DIAGRAM



ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V_{CC}	−0.5~7.0	V
DC Input Voltage	V_{IN}	−0.5~7.0	V
DC Output Voltage	V_{OUT}	−0.5~V_{CC} + 0.5	V
Input Diode Current	I_{IK}	−20	mA
Output Diode Current	I_{OK}	±20	mA
DC Output Current	I_{OUT}	±25	mA
DC V_{CC}/Ground Current	I_{CC}	±50	mA
Power Dissipation	P_D	180	mW
Storage Temperature	T_{stg}	−65~150	°C

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V_{CC}	2.0~5.5	V
Input Voltage	V_{IN}	0~5.5	V
Output Voltage	V_{OUT}	0~V_{CC}	V
Operating Temperature	T_{opr}	−40~85	°C
Input Rise and Fall Time	dt / dv	0~100 (V_{CC} = 3.3 ± 0.3V) 0~20 (V_{CC} = 5 ± 0.5V)	ns / V

DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION		V_{CC} (V)	Ta = 25°C MIN.	Ta = 25°C TYP.	Ta = 25°C MAX.	Ta = −40~85°C MIN.	Ta = −40~85°C MAX.	UNIT
High - Level Input Voltage	V_{IH}			2.0	1.50	−	−	1.50	−	V
				3.0~5.5	V_{CC} × 0.7	−	−	V_{CC} × 0.7	−	
Low - Level Input Voltage	V_{IL}			2.0	−	−	0.50	−	0.50	V
				3.0~5.5	−	−	V_{CC} × 0.3	−	V_{CC} × 0.3	
High - Level Output Voltage	V_{OH}	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50μA	2.0	1.9	2.0	−	1.9	−	V
				3.0	2.9	3.0	−	2.9	−	
				4.5	4.4	4.5	−	4.4	−	
			I_{OH} = −4mA	3.0	2.58	−	−	2.48	−	
			I_{OH} = −8mA	4.5	3.94	−	−	3.80	−	
Low - Level Output Voltage	V_{OL}	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50μA	2.0	−	0.0	0.1	−	0.1	V
				3.0	−	0.0	0.1	−	0.1	
				4.5	−	0.0	0.1	−	0.1	
			I_{OL} = 4mA	3.0	−	−	0.36	−	0.44	
			I_{OL} = 8mA	4.5	−	−	0.36	−	0.44	
Input Leakage Current	I_{IN}	V_{IN} = 5.5V or GND		0~5.5	−	−	±0.1	−	±1.0	μA
Quiescent Supply Current	I_{CC}	V_{IN} = V_{CC} or GND		5.5	−	−	4.0	−	40.0	

TIMING REQUIREMENTS (Input $t_r = t_f = 3ns$)

PARAMETER	SYMBOL	TEST CONDITION		Ta = 25°C	Ta = −40~85°C	UNIT
			V_{CC} (V)	LIMIT	LIMIT	
Minimum Pulse Width (CK, CK INH)	$t_{W(L)}$ $t_{W(H)}$		3.3 ± 0.3 5.0 ± 0.5	6.0 4.0	7.0 4.0	ns
Minimum Pulse Width (S/$\overline{L}$)	$t_{W(L)}$		3.3 ± 0.3 5.0 ± 0.5	7.5 5.0	9.0 6.0	
Minimum Set-up Time (PI−S/$\overline{L}$)	t_s		3.3 ± 0.3 5.0 ± 0.5	7.5 5.0	8.5 5.0	
Minimum Set-up Time (SI−CK, CK INH)	t_s		3.3 ± 0.3 5.0 ± 0.5	5.0 4.0	6.0 4.0	
Minimum Set-up Time (S/$\overline{L}$−CK, CK INH)	t_s		3.3 ± 0.3 5.0 ± 0.5	5.0 4.0	6.0 4.0	
Minimum Hold Time (PI−S/$\overline{L}$)	t_h		3.3 ± 0.3 5.0 ± 0.5	0.5 1.0	0.5 1.0	
Minimum Hold Time (SI−CK, CK INH)	t_h		3.3 ± 0.3 5.0 ± 0.5	0.0 0.5	0.0 0.5	
Minimum Hold Time (S/$\overline{L}$−CK, CK INH)	t_h		3.3 ± 0.3 5.0 ± 0.5	0.0 0.5	0.0 0.5	
Minimum Removal Time (CK INH−CK) (CK−CK INH)	t_{rem}		3.3 ± 0.3 5.0 ± 0.5	5.0 3.5	5.0 3.5	

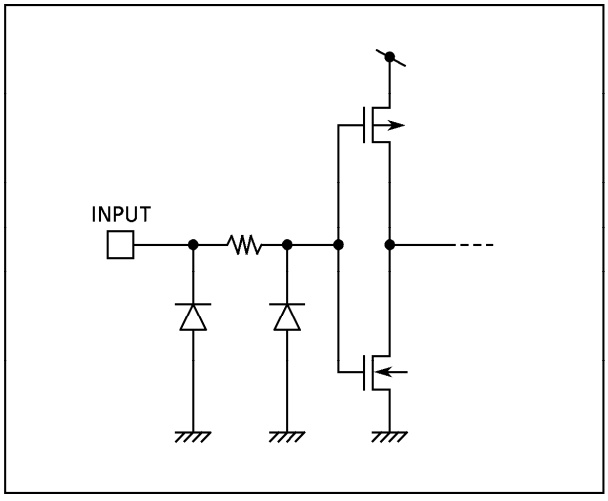
AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3ns$)

PARAMETER	SYMBOL	TEST CONDITION			Ta = 25°C			Ta = −40~85°C		UNIT
			V_{CC} (V)	CL (pF)	MIN.	TYP.	MAX.	MIN.	MAX.	
Propagation Delay Time (CK, CK INH−QH, $\overline{Q}$H)	t_{pLH} t_{pHL}		3.3 ± 0.3	15	—	9.9	15.4	1.0	18.0	ns
				50	—	12.4	18.9	1.0	21.5	
			5.0 ± 0.5	15	—	6.6	9.9	1.0	11.5	
				50	—	8.1	11.9	1.0	13.5	
Propagation Delay Time (S/$\overline{L}$−QH, $\overline{Q}$H)	t_{pLH} t_{pHL}		3.3 ± 0.3	15	—	9.9	15.8	1.0	18.5	
				50	—	12.4	19.3	1.0	22.0	
			5.0 ± 0.5	15	—	6.7	9.9	1.0	11.5	
				50	—	8.2	11.9	1.0	13.5	
Propagation Delay Time (H−QH, $\overline{Q}$H)	t_{pLH} t_{pHL}		3.3 ± 0.3	15	—	9.2	14.1	1.0	16.5	
				50	—	11.7	17.6	1.0	20.0	
			5.0 ± 0.5	15	—	5.9	9.0	1.0	10.5	
				50	—	7.4	11.0	1.0	12.5	
Maximum Clock Frequency	f_{MAX}		3.3 ± 0.3	15	65	85	—	55	—	MHz
				50	60	105	—	50	—	
			5.0 ± 0.5	15	110	150	—	90	—	
				50	95	130	—	85	—	
Input Capacitance	C_{IN}				—	4	10	—	10	pF
Power Dissipation Capacitance	C_{PD}	(Note 1)			—	50	—	—	—	

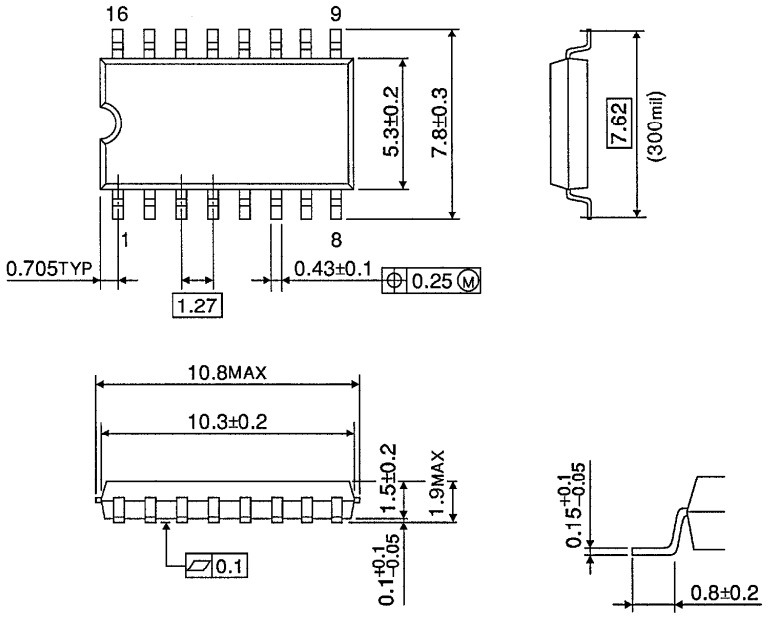
Note (1) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.
Average operating current can be obtained by the equation:

$$I_{CC(opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

INPUT EQUIVALENT CIRCUIT

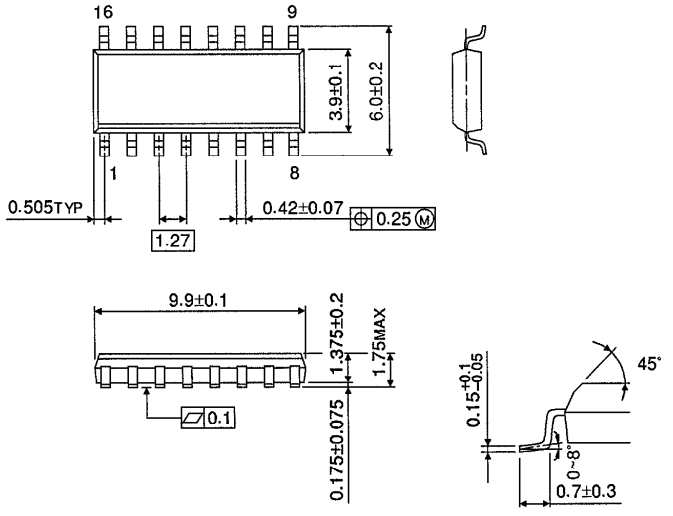


SOP 16PIN (200mil BODY) OUTLINE DRAWING (SOP16-P-300-1.27) Unit in mm



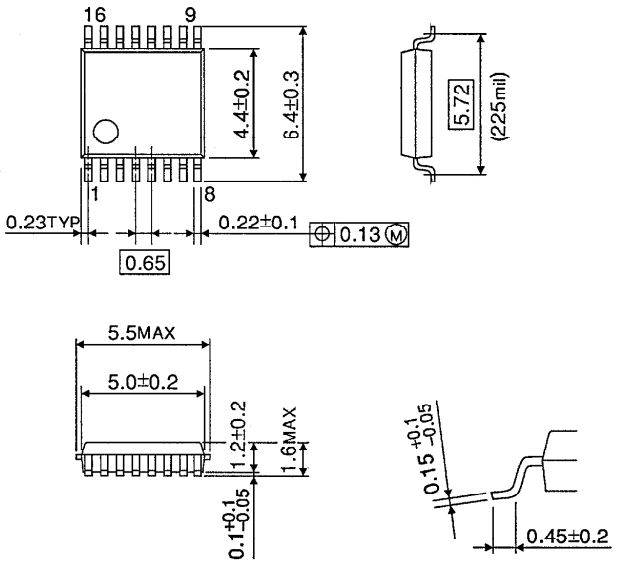
Weight : 0.18g (TYP.)

SOP 16PIN (150mil BODY) OUTLINE DRAWING (SOL16-P-150-1.27) Unit in mm



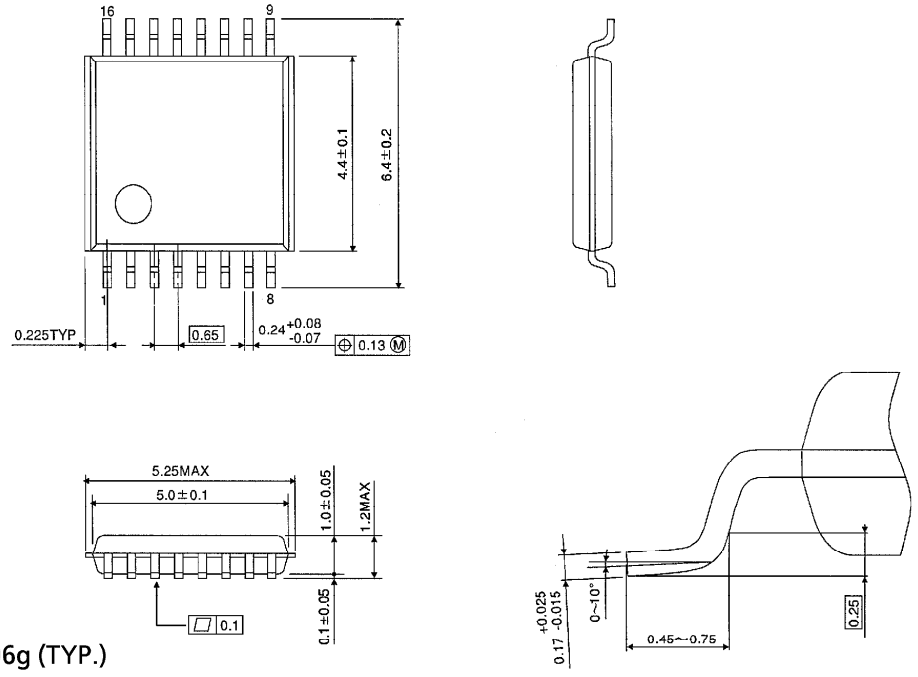
Weight : 0.13g (TYP.)

SSOP 16PIN OUTLINE DRAWING (SSOP16-P-225-0.65B) Unit in mm



Weight : 0.07g (TYP.)

TSSOP 16PIN OUTLINE DRAWING (TSSOP16-P-0044-0.65) Unit in mm



Weight : 0.06g (TYP.)